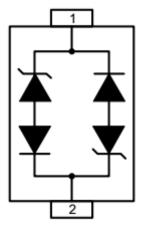


### Description

The JE12B1RS30-2 is a 12V bi-directional TVS diode, utilizing leading monolithic silicon technology to provide fast response time and low ESD clamping voltage, making this device an ideal solution for protecting voltage sensitive high-speed data lines. The JE12B1RS30-2 has a low capacitance with a typical value at 1pF, and complies with the IEC 61000-4-2 (ESD) with  $\pm$ 30kV air and  $\pm$ 30kV contact discharge. It is assembled into a lead-free SOD-323 package. The small size, low capacitance and high ESD surge protection make JE12B1RS30-2 an ideal choice to protect cell phone, wireless systems, and communication equipment.

### **Circuit Diagram**



Circuit and Pin Schematic

## **Marking Diagram**



Transparent top view

R2:Device Marking Code

#### Features

- \* 350W peak pulse power (8/20µs)
- \* Low leakage:nA level
- \* Operating voltage: 12V
- \* Ultra Low clamping voltage
- \* Protects one power line or data line
- \* Complies with following standards:

- IEC 61000-4-2 (ESD) immunity test

Air discharge: ±30kV

Contact discharge: ±30kV

- IEC61000-4-5 (Lightning) 14A (8/20µs)
- \* RoHS Compliant
- Package:SOD-323

### Applications

- \* USB Ports
- \* Smart Phones
- \* Wireless Systems
- \* Ethernet 10/100/1000 Base T

## **Ordering Information**

Part Number	Packaging	<b>Reel Size</b>	
JE12B1RS30-2	3000/Tape & Reel	7 inch	



# Absolute Maximum Ratings (T<sub>A</sub>=25°C unless otherwise specified)

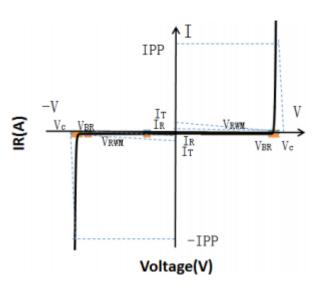
Parameter	Symbol	Value	Unit
Peak Pulse Power (8/20µs)	Ppk	350	W
Peak Pulse Current (8/20µs)	IPP	14	А
ESD per IEC 61000-4-2 (Air)	VESD	±30	1-17
ESD per IEC 61000-4-2 (Contact)	VESD	±30	kV
Operating Temperature Range	TJ	-55to +125	°C
Storage Temperature Range	Tstg	-55 to +150	°C

# **Electrical Characteristics (T<sub>A</sub>=25°C unless otherwise specified)**

Parameter	Symbol	Test Condition	Min	Тур	Max	Unit
Reverse Working Voltage	Vrwm				12	V
Breakdown Voltage	VBR	$I_T = 1 m A$	12			V
Reverse Leakage Current	I <sub>R</sub>	$V_{RWM} = 3.3V$			0.2	uA
Clamping Voltage	Vc	$I_{PP} = 1A (8 \times 20 \mu s \text{ pulse})$			18	V
Clamping Voltage	Vc	$I_{PP} = 14A (8 \times 20 \mu s \text{ pulse})$			25	V
Junction Capacitance	Сл	VR = 0V, f = 1MHz,)		1		pF

## **Portion Electronics Parameter**

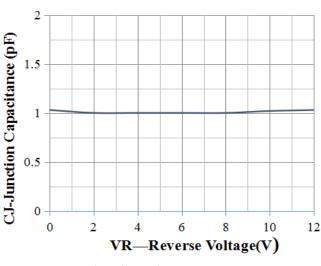
Symbol	Parameter	
Ιτ	Test Current	
Ірр	Maximum Reverse Peak Pulse Current	
Vc	Clamping Voltage @Ic	

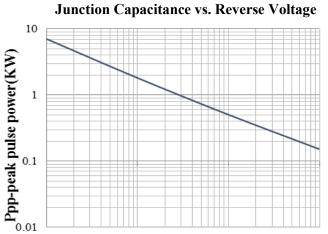


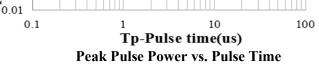
### JE12B1RS30-2

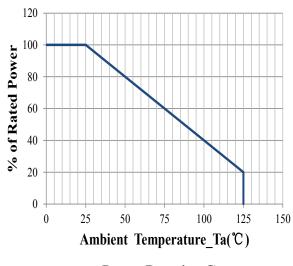


# Typical Performance Characteristics (T<sub>A</sub>=25°C unless otherwise Specified)

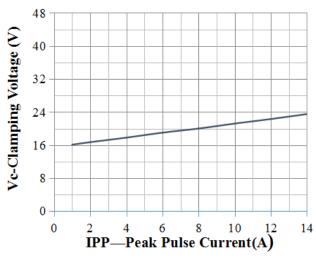




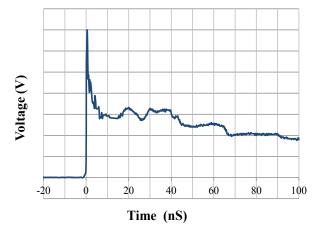




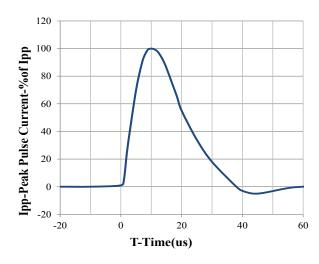
**Power Derating Curve** 



**Clamping Voltage vs. Peak Pulse Current** 



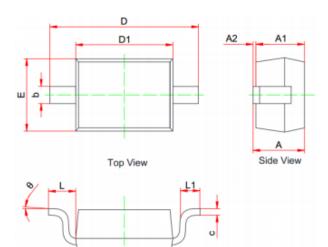
IEC61000-4-2 Pulse Waveform



8 X 20us Pulse Waveform

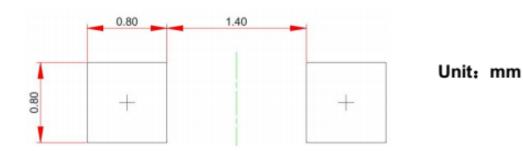


### **SOD-323** Package Outline Drawing (Dimensions in millimeters)



	MILLIMETERS		
SYM	MIN	NOM	MAX
А	0.800		1.100
A1	0.800		0.900
A2	0.000		0.100
b	0.250		0.400
с	0.080		0.177
D1	1.600	1.700	1.800
D	2.300		2.800
Е	1.150		1.400
L		0.475REF	-
L1	0.100		0.500
Θ	0°		8°

### **Suggested Land Pattern**



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